

DOCKET NO: 288839US0PCT

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
EKKEHARD MUEH, ET AL. : ATTN: APPLICATION DIVISION
SERIAL NO: NEW U.S. PCT APPLICATION :
(BASED ON PCT/EP04/53669)
FILED: HERewith :
FOR: SILICON COMPOUNDS FOR :
PRODUCING SiO₂-CONTAINING :
INSULATING LAYERS ON CHIPS

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.